## NSN 5961-01-317-5100

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-317-5100 **Inclosure Material:** Plastic **Overall Length:** 0.785 inches **Terminal Length:** 0.125 inches **Overall Height:** 0.200 inches **Overall Width:** Between 0.220 inches and 0.310 inches **Component Name And Quantity:** 4 transistor **Mounting Method: Terminal Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 75.0 collector to base voltage/static/emitter open all transistor and 50.0 collector to emitter voltage/static/base open all transistor and 6.0 emitter to base voltage, static, collector open all transistor **Current Rating Per Characteristic:** 800.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 1.5 watts small-signal input power, common-collector preset all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** All transistor junction pattern arrangement: npn **Test Data Document:** 81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 14 printed circuit **Specification Data:** 81349-mil-prf-19500/559 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

Mil-std (military Standard):

No Fiig: A110a0